#### ΡΛΝ SEM CONDUCTOR

TO-252AA

(2)

3

Gate <sup>①</sup>

Drain

Source

# **PJD35P03**

### **30V P-Channel Enhancement Mode MOSFET**

Voltage

-30 V Current

### Features

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-10V,I<sub>D</sub>@-8A<19mΩ
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-4.5V,I<sub>D</sub>@-5A<30mΩ</li>
- High switching speed
- Improved dv/dt capability •
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

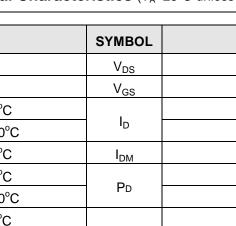
- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0104 ounces, 0.297grams

### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

-35 A

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-30	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	l <sub>D</sub>	-35		
	T <sub>C</sub> =100°C		-22	А	
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	-140		
Power Dissipation	T <sub>C</sub> =25°C	Po	35	14/	
	$T_c=100^{\circ}C$		14	W	
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	-8.4	А	
	T <sub>A</sub> =70°C		-6.7	А	
Power Dissipation	T <sub>A</sub> =25°C	D	2.0	14/	
Power Dissipation	T <sub>A</sub> =70°C	PD	1.3	W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{ extsf{ heta}JC}$	3.6	°C/W	
	Junction to Ambient	R <sub>θJA</sub>	62.5		

Limited only By Maximum Junction Temperature





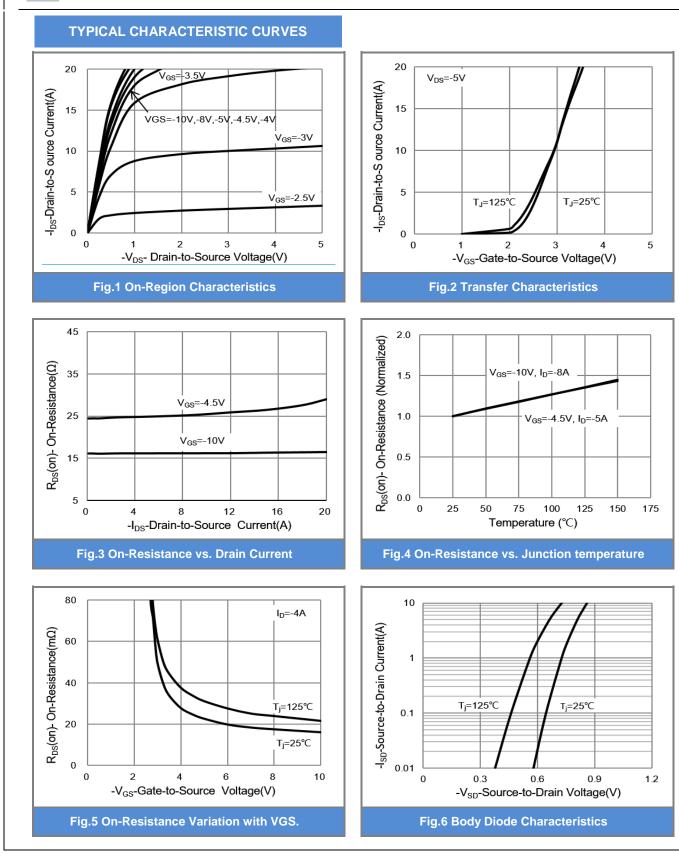
### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-30	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=-250$ uA	-1	-1.5	-2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-8A	-	15	19	mΩ
		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-5A	-	24	30	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V,V <sub>GS</sub> =0V	-	-	-1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	$V_{DS}$ =-15V, I <sub>D</sub> =-5A, V <sub>GS</sub> =-4.5V <sup>(Note 1,2)</sup>	-	11	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	3.2	-	
Gate-Drain Charge	$Q_{gd}$		-	3.9	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1169	-	pF
Output Capacitance	Coss		-	180	-	
Reverse Transfer Capacitance	Crss		-	132	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	5.9	-	ns
Turn-On Rise Time	t <sub>r</sub>	V <sub>DS</sub> =-15V,ID=-1A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω (Note 1,2)	-	33	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	55	-	
Turn-Off Fall Time	t <sub>f</sub>	(	-	34	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I <sub>S</sub>		-	-	-35	А
Diode Forward Current	'5		<b>_</b>			
Reverse Recovery Time	$V_{SD}$	I <sub>S</sub> =-1A,V <sub>GS</sub> =0V	-	-0.73	-1.0	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150$ °C. Ratings are based on low frequency and duty cycles to keep initial  $T_J = 25$ °C.
- 4. The maximum current rating is package limited
- 5. R<sub>®JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.







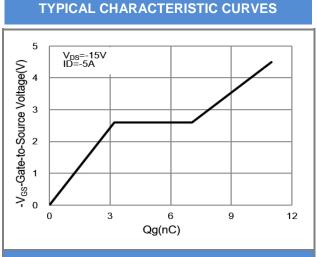
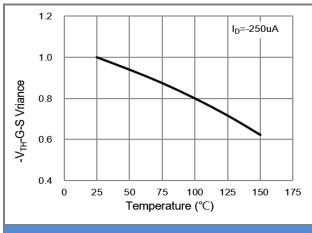
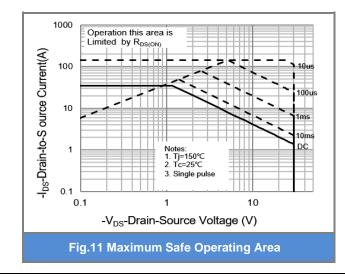
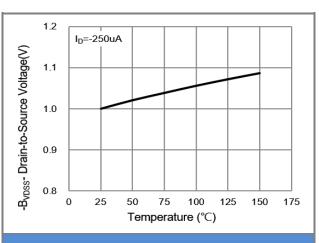


Fig.7 Gate-Charge Characteristics











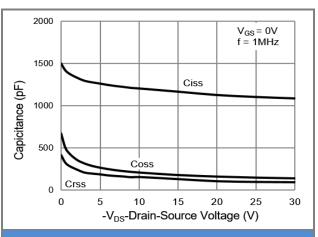
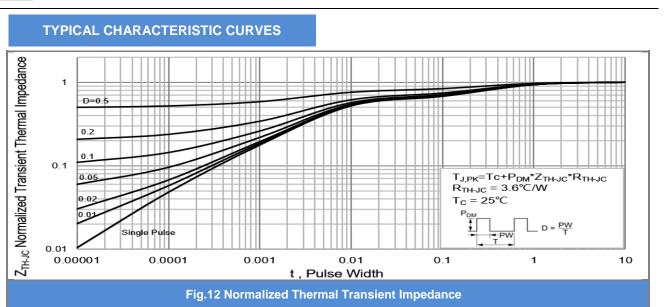
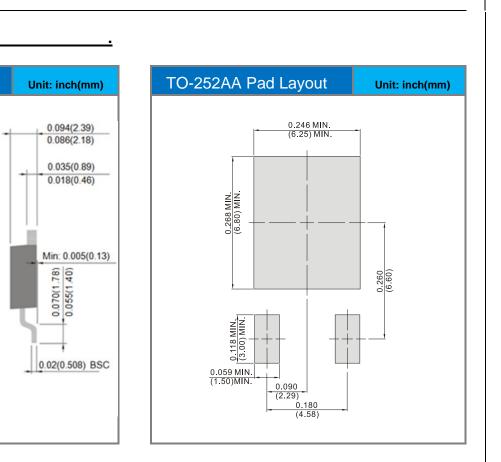


Fig.10 Capacitance vs. Drain-Source Voltage.









#### **Packaging Information**

**TO-252AA Dimension** 

0.265(6.73)

0.250(6.35)

0.215(5.46)

0.195(4.95)

4

0

3

0.035(0.89)

0.09(2.29)

1

0.09(2.29)

0.050(1.27) 0.035(0.89)

0.245(6.22) 0.235(5.97)

0.108(2.74) BSC



### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD35P03_L2_00001	TO-252AA	3,000pcs / 13" reel	D35P03	Halogen free



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